Switch Mode Power Rectifiers

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

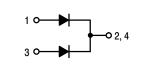
- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- These are Pb–Free Devices*
- **Mechanical Characteristics:**
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

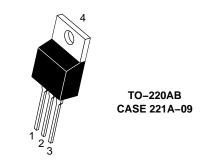


ON Semiconductor®

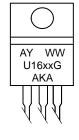
www.onsemi.com

ULTRAFAST RECTIFIERS 16 AMPERES, 100–600 VOLTS





MARKING DIAGRAM



A = Assembly Location

- Y = Year WW = Work Week
- U16xx = Device Code
 - xx = 10, 15, 20, 40 or 60
- G = Pb–Free Package
- KA = Diode Polarity

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

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MAXIMUM RATINGS

			MUR16					
Rating		Symbol	10CT	15CT	20CT	40CT	60CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	150	200	400	600	V
Average Rectified Forward Current Total Device, (Rated V _R), T _C = 150°C	Per Leg Total Device	I _{F(AV)}	8.0 16			A		
Peak Rectified Forward Current (Rated V_R , Square Wave, 20 kHz), $T_C = 150^{\circ}C$ Per Diode Leg		I _{FM}	16					A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	100					A
Operating Junction Temperature and Storage Temperature		T _J , T _{stg}	- 65 to +175					°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	Value	Unit	
Maximum Thermal Resistance, Junction-to-Case	R_{\thetaJC}	3.0	2.0	°C/W

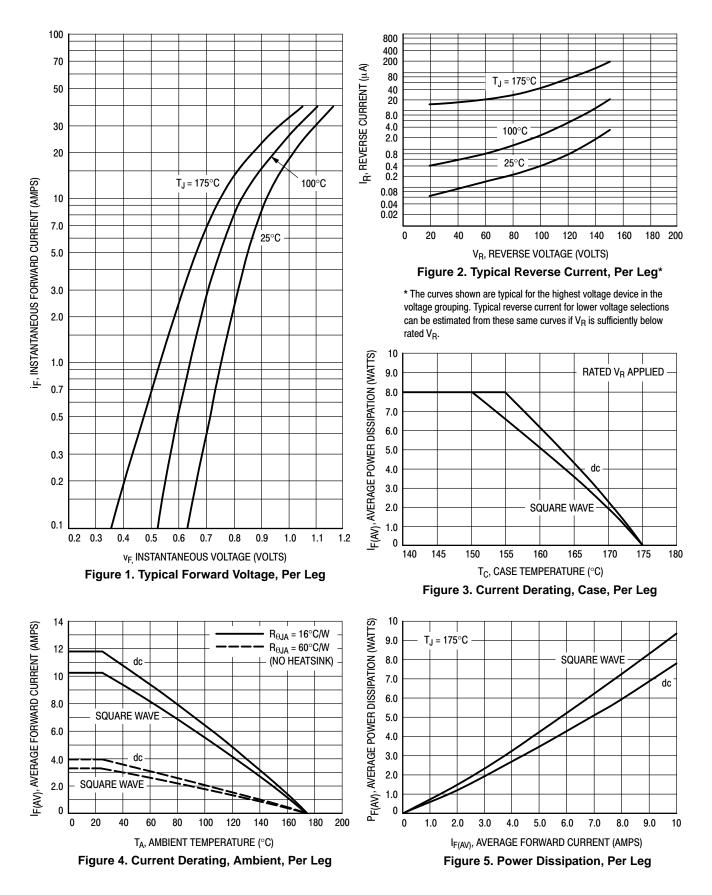
ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	1620	1640	1660	Unit
Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$) ($i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$)	۷F	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 150^{\circ}C$) (Rated DC Voltage, $T_C = 25^{\circ}C$)	İR	250 5.0	500 10		μΑ
	t _{rr}	35 25	60 50		ns

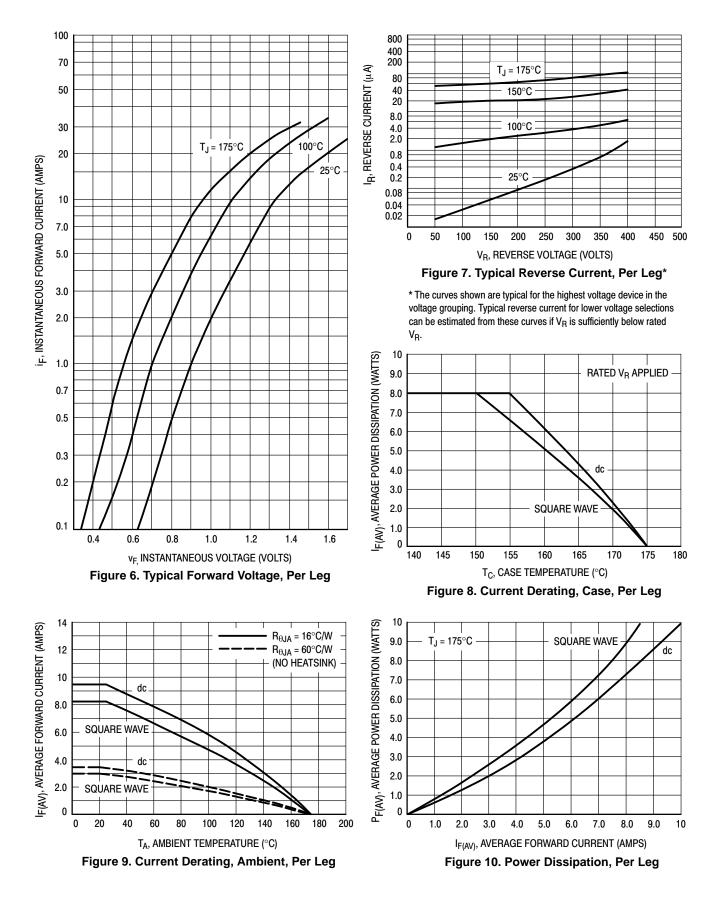
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%

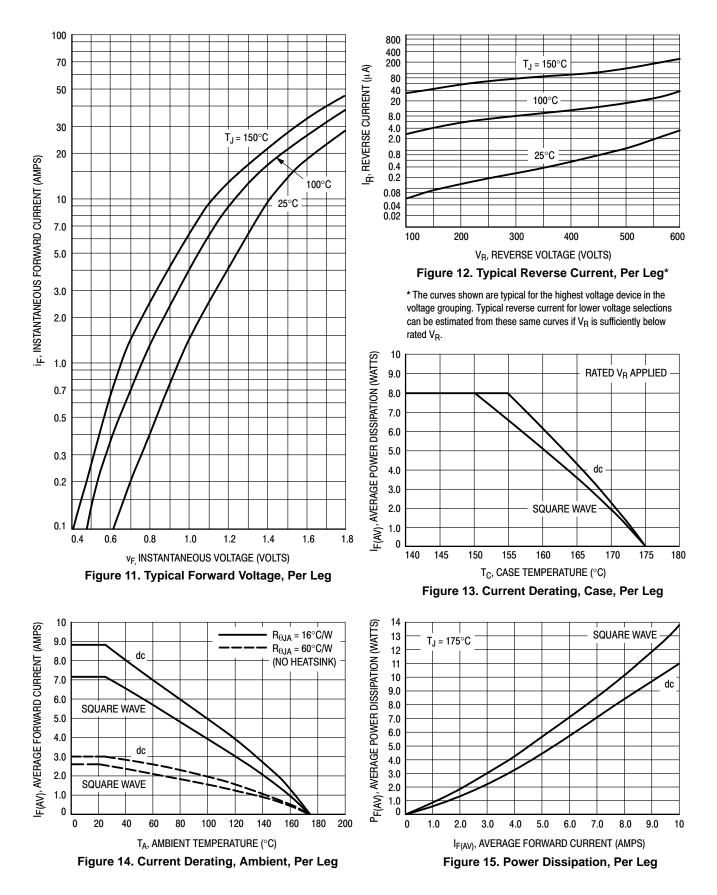
MUR1610CT, MUR1615CT, MUR1620CT

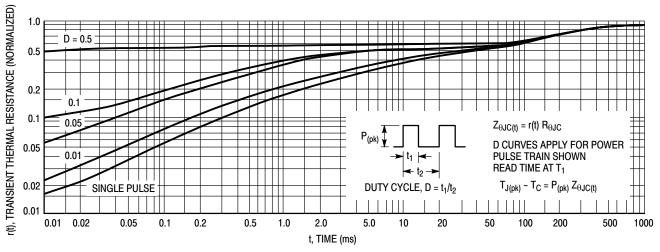


MUR1640CT



MUR1660CT







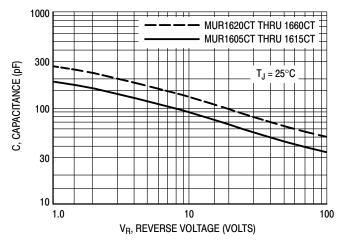


Figure 17. Typical Capacitance, Per Leg

ORDERING INFORMATION

Device	Package	Shipping [†]
MUR1610CTG	TO-220 (Pb-Free)	
MUR1615CTG	TO-220 (Pb-Free)	
MUR1620CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1640CTG	TO-220 (Pb-Free)	
MUR1660CTG	TO-220 (Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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SCALE 1:1		TO-22 CASE 22 ISSUE	21A AK SEATING PLANE	2. Cont 3. dimen Leai	ROLLING D NSION Z DE D IRREGUL/	AND TOLERAI IMENSION: IN FINES A ZONI ARITIES ARE A F102 DEVICE	ICHES E WHERE AL ALLOWED.	ANSI Y14.5№	
				4. MAX V	WIDTH FOR	F102 DEVICE	= 1.3510101		
	I	Γ I			INC	HES	MILLIM	ETERS	
				DIM	MIN.	MAX.	MIN.	MAX.	
	2 3			А	0.570	0.620	14.48	15.75	
<u> </u>	┟┰┟┟╌┙──┼			В	0.380	0.415	9.66	10.53	
⊢	₩+₩++			С	0.160	0.190	4.07	4.83	
	í lí	f I		D	0.025	0.038	0.64	0.96	
' z –	I I K			F	0.142	0.161	3.60	4.09	
	î î			G	0.095	0.105	2.42	2.66	
				н	0.110	0.161	2.80	4.10	
	¥ ₩	ü l		J	0.014	0.024	0.36	0.61	
V —	R —			ĸ	0.500	0.562	12.70 1.15	14.27	
G	J-	╼║╼		N	0.045	0.060	4.83	1.52 5.33	
Ŭ,	' → → D			Q	0.190	0.210	2.54	3.04	
_	N -			R	0.100	0.120	2.54	2.79	
				s	0.030	0.055	1.15	1.41	
				т	0.235	0.255	5.97	6.47	
				U U	0.000	0.050	0.00	1.27	
				v	0.045		1.15		
				z		0.080		2.04	
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